

Transport properties in layered thermoelectric chalcogenides

Intercalation, substitution and non stochiometry : three different approaches to increase phonon scattering in TiS_2

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Emmanuel Guilmeau

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Summary



- 1. MS₂ Layered Dichalcogenides
- 2. Intercalation : the case of copper and silver
- Heavy metal cations Substitution (Ta, Nb)
- 4. Non-stochiometry: Tuning of TE properties and structural disordering

MS₂ Layered Structure

Trigonal prismatic or octahedral
Hexagonal packed planes
Van-der-Waals interaction between layers
Alkali, Metal intercalation

Electronic Properties

Insulating-SC-Metal
Degree of filling of d bands (metal)
Non stoichiometry



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J.A.Wilson and A.D. Yoffe, Adv. Phys (1969)



Non-stochiometry

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Electronic Properties

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Strong Anisotropy

Two-dimensional character, e.g. electrical and thermal properties
Electron mobility in Cdl₂ planes
Phonon scattering along c direction



$[Ca_2CoO_3]_{0.62}[CoO_2]$



An Oxide Single Crystal with High Thermoelectric Performance in Air

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Misfit-layered cobaltite with an anisotropic giant magnetoresistance: Ca₃Co₄O₉

A. C. Masset, C. Michel,* A. Maignan, M. Hervieu, O. Toulemonde, F. Studer, and B. Raveau Laboratoire CRISMAT, UMR 6508 associée au CNRS, ISMRA et Université de Caen 6, Boulevard du Maréchal Juin, 14050 CAEN Cedex, France

J. Hejtmanek Laboratory of Oxidic Materials, Institute of Physics, 162 53 Prague 6, Cukrovarnicka 10, Czech Republic (Received 1 February 2000)

A. C. Masset et al., PR B 62, 166, 2000 R. Funahashi et al., JJAP 39, L1127, 2000 $\rightarrow S = +120 \mu V/K$





Substitution

Non-stochiometry

Why TiS_2 as a TE element?

Criteria for thermoelectricty

Narrow band-gap semiconductor

Low electrical resistivity, high Seebeck coefficient

n= 10²⁰ cm⁻³ High Power factor 1.7 mW/mK² @ 300K

Flexible compositions for tuning transport properties
Optimum carrier concentration

Large unit cell, complex structure, disorder Low thermal conductivity



Low thermal conductivity





Substitution

Non-stochiometry

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Material Processing

Powder

Sealed tube synthesis (650°C/12h)

Grain size (5 μm)

Traces of TiO₂



MS₂ compounds

Intercalation

Bulk



SPS Sintering 600-900°C 50-300 MPa

Relative Density > 95%

> Grain size (20 µm)

Slight (001) texture

Substitution

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Substitution

Non-stochiometry

Intercalation in TiS₂

Synthesis and Structure

MS₂ compounds

 Copper diffusion by In Situ SPS
High density (>95%)
Slight (001) texture
c cell parameter increase
TEM: Elongated dot reflexion →Disorder

Intercalation



Electrical Properties



Electrical Properties



Thermal Properties



 $Ag_{x}TiS_{2}$

Different Intercalation mechanism
Increase in ZT up to 0.46 @ 700K



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Solid Solution $Ti_{1-x}Ta_xS_2$, $Ti_{1-x}Nb_xS_2$







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Ti_{1+x}S₂: Non stochiometry Approach



$Ti_{1+x}S_2$: Non stochiometry Approach

Tuned carrier concentrationWide range of Seebeck coeff.

□ Drastic decrease in κ_{tot} □ Ti intercalation → disorder □ ZT improved up to 0.45 @ 700K





Conclusion

1. Intercalation, Substitution, Non Stochiometry Three potential approachs to decrease kappa.

- **2.** Progress achieved with ZT>0.5 @ 700K
- **3.** More efforts required to double ZT in the temperature range RT-700K

Conclusion



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Thank you for your attention!!!!